
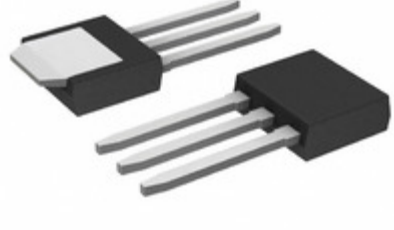





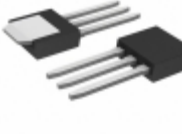


	<p>NTD85N02R-001</p>
	<p>Hersteller-Teilenummer: NTD85N02R-001</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 24V 12A IPAK</p> <p>Datenblätter:  NTD85N02R-001.pdf</p> <p>RoHs Status: Enthält Blei / RoHS nicht konform</p> <p>Lagerzustand: New original, 14018 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD85N02R-001
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 24V 12A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	14018 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.25W (Ta), 78.1W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	24V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Ta), 85A (Tc)
Rds On (Max) @ Id, Vgs	5.2 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17.7nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	2050pF @ 20V
Verpackung	Tube



















































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Sie können auch interessiert sein:

 <p>NTD85N02RG AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12A DPAK</p>	 <p>NTD85N02-1G ON NTD85N02-1G ON</p>	 <p>NTD85N02G ON NTD85N02G ON</p>	 <p>NTD85N02RT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12A DPAK</p>
 <p>NTD85N02R-1 ON/ NTD85N02R-1 ON/</p>	 <p>NTD85N02R-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12A IPAK</p>	 <p>NTD85N02 ON NTD85N02 ON</p>	 <p>NTD85N02R14 ON NTD85N02R14 ON</p>

heiße Teile

Mehr

 NTD70N03	 NTD70N03R	 NTD70N03R-001	 NTD70N03R-1	 NTD70N03R-1G
 NTD70N03RG	 NTD70N03RT4	 NTD70N03RT4G	 NTD70N03TR4	 NTD78N03
 NTD78N03-001	 NTD78N03-035	 NTD78N03-1	 NTD78N03-1G	 NTD78N03-35G
 NTD78N03R-001	 NTD78N03R-1G	 NTD78N03RT4G	 NTD78N03T4	 NTD78N03T4G
 NTD80N02	 NTD80N02-001	 NTD80N02-1	 NTD80N02-1G	 NTD80N02G
 NTD80N02T4	 NTD80N02T4G	 NTD85N02-1G	 NTD85N02R	 NTD85N02R-1
 NTD85N02R-1G	 NTD85N02R14	 NTD85N02RG	 NTD85N02RT4G	 NTD85N02T4G
 NTD95N02-001	 NTD95N02-1G	 NTD95N02R	 NTD95N02R-1G	 NTD95N02RG
 NTD95N02RT4G	 NTDV18N06LT4G	 NTDV20N06LT4G	 NTDV20N06T4G	 NTDV20P06LT4G
 NTDV20P06LT4G	 NTDV2955PT4G	 NTDV3055L104T4G	 NTDV5804NT4G	 NTDV5805NT4G

Contact us: Info@Y-IC.com

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